RoHS

COMPLIANT

HALOGEN

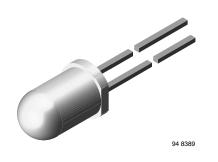
GREEN

(5-2008)



Vishay Semiconductors

High Power Infrared Emitting Diode, 940 nm, GaAlAs, MQW



DESCRIPTION

TSAL6400 is an infrared, 940 nm emitting diode in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed

molded in a blue-gray plastic package.

FEATURES

- · Package type: leaded
- Package form: T-1³/₄
- Dimensions (in mm): Ø 5
- Peak wavelength: $\lambda_p = 940 \text{ nm}$
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: $\phi = \pm 25^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Infrared remote control units with high power requirements
- Free air transmission systems
- Infrared source for optical counters and card readers

PRODUCT SUMMARY COMPONENT Ie (mW/sr) φ (deg) λp (nm) tr (ns) TSAL6400 50 ± 25 940 15

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

UNDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
TSAL6400	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V _R	5	V			
Forward current		I _F	100	mA			
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA			
Surge forward current	t _p = 100 μs	I _{FSM}	1.5	A			
Power dissipation		Pv	160	mW			
Junction temperature		Тj	100	°C			
Operating temperature range		T _{amb}	-40 to +85	°C			
Storage temperature range		T _{stg}	-40 to +100	°C			
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C			
Thermal resistance junction/ambient	J-STD-051, leads 7 mm soldered on PCB	R _{thJA}	230	K/W			

1 For technical questions, contact: <u>emittertechsupport@vishay.com</u> Document Number: 81011

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

Vishay Semiconductors

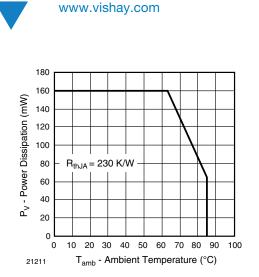


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

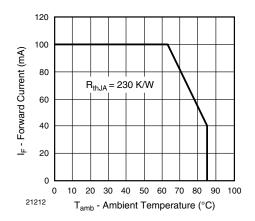


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	l _F = 100 mA, t _p = 20 ms	V _F		1.35	1.6	V	
	I _F = 1 A, t _p = 100 μs	V _F		2.2	3	V	
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		-1.8		mV/K	
Reverse current	$V_R = 5 V$	I _R			10	μA	
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		40		pF	
Dedient interaity	l _F = 100 mA, t _p = 20 ms	l _e	25	50	125	mW/sr	
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e	220	420		mW/sr	
Radiant power	l _F = 100 mA, t _p = 20 ms	фе		40		mW	
Temperature coefficient of ϕ_e	I _F = 20 mA	TKφ _e		-0.6		%/K	
Angle of half intensity		φ		± 25		deg	
Peak wavelength	I _F = 100 mA	λρ		940		nm	
Spectral bandwidth	I _F = 100 mA	Δλ		30		nm	
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλρ		0.2		nm/K	
Rise time	I _F = 100 mA	t _r		15		ns	
Fall time	I _F = 100 mA	t _f		15		ns	

For technical questions, contact: <u>emittertechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

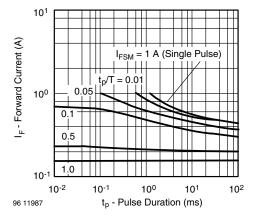


Fig. 3 - Pulse Forward Current vs. Pulse Duration

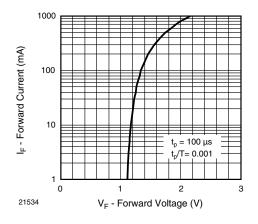


Fig. 4 - Forward Current vs. Forward Voltage

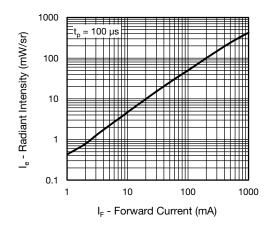


Fig. 5 - Radiant Intensity vs. Forward Current

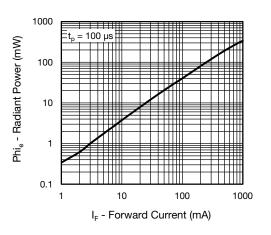


Fig. 6 - Radiant Power vs. Forward Current

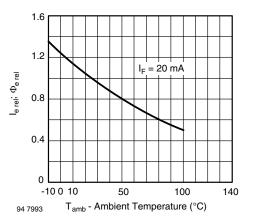


Fig. 7 - Relative Radiant Intensity/Power vs. Ambient Temperature

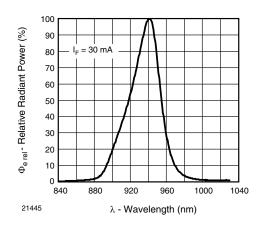


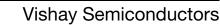
Fig. 8 - Relative Radiant Power vs. Wavelength

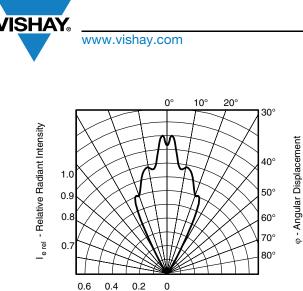
Rev. 2.0, 13-Mar-14

3 contact: cmittart Document Number: 81011

For technical questions, contact: <u>emittertechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



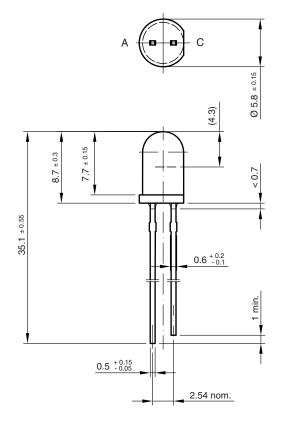


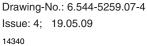


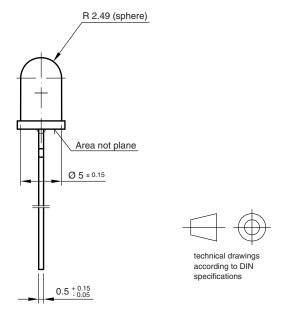
14330

Fig. 9 - Relative Radiant Intensity vs. Angular Displacement









Rev. 2.0, 13-Mar-14

4

For technical questions, contact: <u>emittertechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.